ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage (Note 2)	TIP41, TIP42	V _{CEO(sus)}	40	_	Vdc
$(I_C = 30 \text{ mAdc}, I_B = 0)$	TIP41A, TIP42A	,	60	-	
	TIP41B, TIP42B		80	-	
	TIP41C, TIP42C		100	-	
Collector Cutoff Current		I _{CEO}			mAdc
$(V_{CE} = 30 \text{ Vdc}, I_B = 0)$	TIP41, TIP41A, TIP42, TIP42A		_	0.7	
$(V_{CE} = 60 \text{ Vdc}, I_{B} = 0)$	TIP41B, TIP41C, TIP42B, TIP42C		-	0.7	
Collector Cutoff Current		I _{CES}			μAdc
$(V_{CE} = 40 \text{ Vdc}, V_{EB} = 0)$	TIP41, TIP42		_	400	
$(V_{CE} = 60 \text{ Vdc}, V_{EB} = 0)$	TIP41A, TIP42A		-	400	
$(V_{CE} = 80 \text{ Vdc}, V_{EB} = 0)$	TIP41B, TIP42B		_	400	
$(V_{CE} = 100 \text{ Vdc}, V_{EB} = 0)$	TIP41C, TIP42C		-	400	
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}$, $I_{C} = 0$)		I _{EBO}	-	1.0	mAdc
ON CHARACTERISTICS (Note 2)					
DC Current Gain (I _C = 0.3 Adc, V _{CE} = 4.0 Vdc)		h _{FE}	30	_	_
$(I_C = 3.0 \text{ Adc}, V_{CE} = 4.0 \text{ Vdc})$			15	75	
Collector–Emitter Saturation Voltage (I _C = 6.0 Adc, I _B = 600 mAdc)		V _{CE(sat)}	-	1.5	Vdc
Base-Emitter On Voltage (I _C = 6.0 Adc, V _{CE} = 4.0 Vdc)		V _{BE(on)}	-	2.0	Vdc
DYNAMIC CHARACTERISTICS					
Current-Gain — Bandwidth Product (I _C = 500 mAdc, V _{CE} = 10 Vdc, f _{test} = 1.0 MHz)			3.0	-	MHz
Small-Signal Current Gain (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 1.0 kHz)		h _{fe}	20	_	-

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

ORDERING INFORMATION

Device	Package	Shipping	
TIP41	TO-220	50 Units / Rail	
TIP41G	TO-220 (Pb-Free)	50 Units / Rail	
TIP41A	TO-220	50 Units / Rail	
TIP41AG	TO-220 (Pb-Free)	50 Units / Rail	
TIP41B	TO-220	50 Units / Rail	
TIP41BG	TO-220 (Pb-Free)	50 Units / Rail	
TIP41C	TO-220	50 Units / Rail	
TIP41CG	TO-220 (Pb-Free)	50 Units / Rail	
TIP42	TO-220	50 Units / Rail	
TIP42G	TO-220 (Pb-Free)	50 Units / Rail	
TIP42A	TO-220	50 Units / Rail	
TIP42AG	TO-220 (Pb-Free)	50 Units / Rail	
TIP42B	TO-220	50 Units / Rail	
TIP42BG	TO-220 (Pb-Free)	50 Units / Rail	
TIP42C	TO-220	50 Units / Rail	
TIP42CG	TO-220 (Pb-Free)	50 Units / Rail	

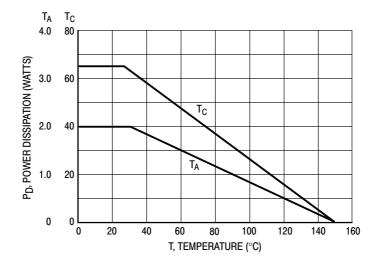
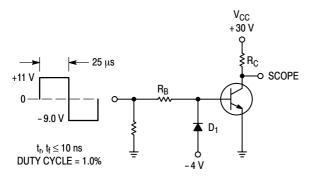


Figure 1. Power Derating

2.0

1.0



 R_B and R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS D $_1$ MUST BE FAST RECOVERY TYPE, e.g.: $1N5825~USED~ABOVE~I_B\approx 100~mA\\ MSD6100~USED~BELOW~I_B\approx 100~mA$

V_{CC} = 30 V 0.7 $I_{\rm C}/I_{\rm B} = 10$ 0.5 t, TIME (µs) 0.3 0.2 0.1 0.07 $t_d \ @ \ V_{BE(off)} \approx 5.0 \ V$ 0.05 0.03 0.02 0.06 0.1 0.4 0.6 1.0 2.0 4.0 6.0 IC, COLLECTOR CURRENT (AMP)

 $T_J = 25^{\circ}C$

Figure 3. Turn-On Time

Figure 2. Switching Time Test Circuit

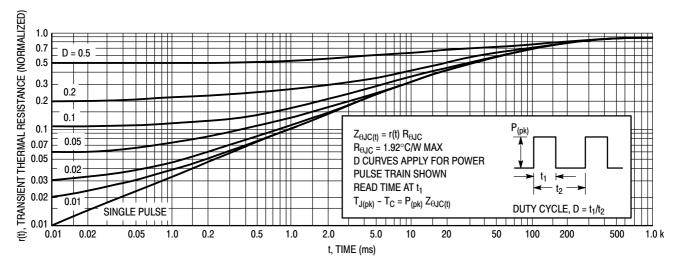


Figure 4. Thermal Response

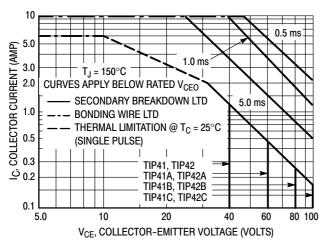


Figure 5. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

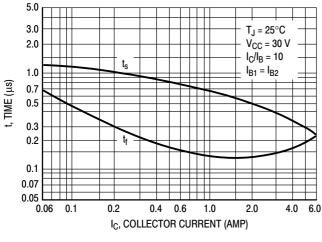


Figure 6. Turn-Off Time

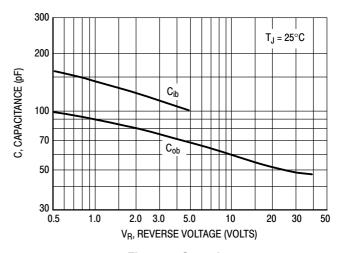


Figure 7. Capacitance

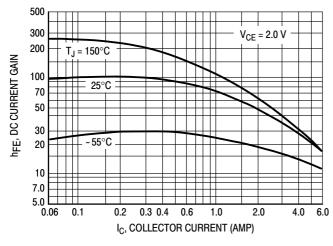


Figure 8. DC Current Gain

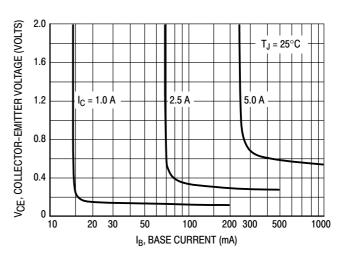


Figure 9. Collector Saturation Region

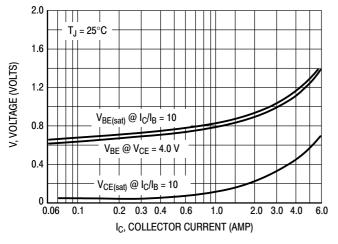


Figure 10. "On" Voltages

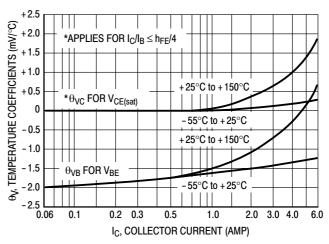


Figure 11. Temperature Coefficients

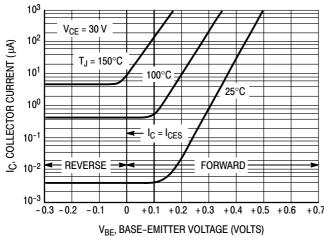


Figure 12. Collector Cut-Off Region

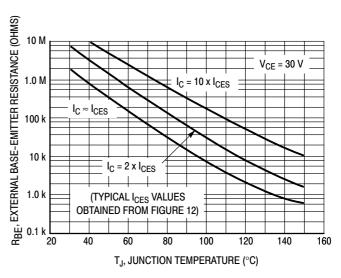
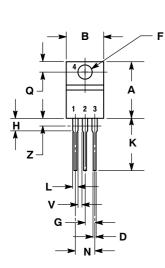
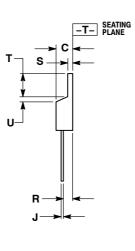


Figure 13. Effects of Base-Emitter Resistance

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AG**





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.036	0.64	0.91	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.161	2.80	4.10	
J	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 1:

PIN 1. BASE

COLLECTOR

EMITTER

COLLECTOR

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